
HD74ALVCH16825

18-bit Buffers / Drivers with 3-state Outputs

HITACHI

ADE-205-172A (Z)
2nd. Edition
December 1999

Description

The HD74ALVCH16825 improves the performance and density of 3-state memory address drivers, clock drivers, and bus-oriented receivers and transmitters. The device can be used as two 9-bit buffers or one 18-bit buffer. It provides true data. The 3-state control gate is a 2-input AND gate with active low inputs so that if either output enable ($\overline{OE1}$ or $\overline{OE2}$) input is high, all nine affected outputs are in the high impedance state. Active bus hold circuitry is provided to hold unused or floating data inputs at a valid logic level.

Features

- $V_{CC} = 2.3\text{ V}$ to 3.6 V
- Typical V_{OL} ground bounce $< 0.8\text{ V}$ ($@V_{CC} = 3.3\text{ V}$, $T_a = 25^\circ\text{C}$)
- Typical V_{OH} undershoot $> 2.0\text{ V}$ ($@V_{CC} = 3.3\text{ V}$, $T_a = 25^\circ\text{C}$)
- High output current $\pm 24\text{ mA}$ ($@V_{CC} = 3.0\text{ V}$)
- Bus hold on data inputs eliminates the need for external pullup / pulldown resistors

Function Table

Inputs			Output Y
$\overline{OE1}$	$\overline{OE2}$	A	
L	L	L	L
L	L	H	H
H	X	X	Z
X	H	X	Z

H : High level

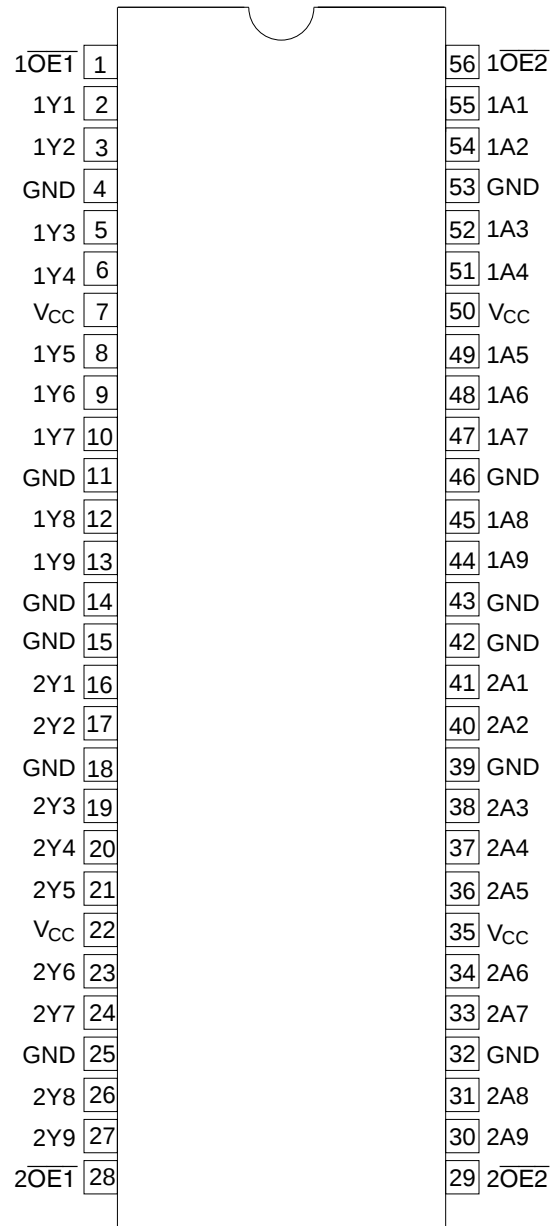
L : Low level

X : Immaterial

Z : High impedance

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Pin Arrangement



(Top view)

Absolute Maximum Ratings

Item	Symbol	Ratings	Unit	Conditions
Supply voltage	V_{CC}	−0.5 to 4.6	V	
Input voltage ^{*1}	V_I	−0.5 to 4.6	V	
Output voltage ^{*1, 2}	V_O	−0.5 to $V_{CC} + 0.5$	V	
Input clamp current	I_{IK}	−50	mA	$V_I < 0$
Output clamp current	I_{OK}	±50	mA	$V_O < 0$ or $V_O > V_{CC}$
Continuous output current	I_O	±50	mA	$V_O = 0$ to V_{CC}
		±100		
Maximum power dissipation at $T_a = 55^\circ\text{C}$ (in still air) ^{*3}	P_T	1	W	TSSOP
Storage temperature	T_{stg}	−65 to 150	$^\circ\text{C}$	

Notes: Stresses beyond those listed under “absolute maximum ratings” may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under “recommended operating conditions” is not implied. Exposure to absolute maximum rated conditions for extended periods may affect device reliability.

1. The input and output negative voltage ratings may be exceeded if the input and output clamp current ratings are observed.
2. This value is limited to 4.6 V maximum.
3. The maximum package power dissipation is calculated using a junction temperature of 150°C and a board trace length of 750 mils.

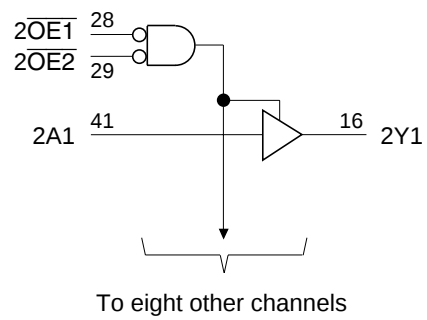
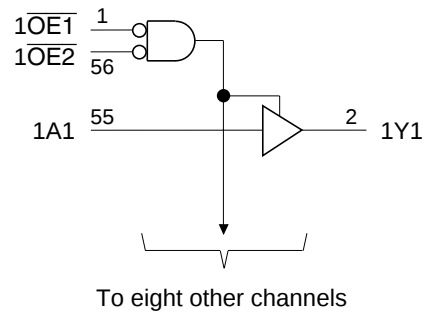
Recommended Operating Conditions

Item	Symbol	Min	Max	Unit	Conditions
Supply voltage	V_{CC}	2.3	3.6	V	
Input voltage	V_I	0	V_{CC}	V	
Output voltage	V_O	0	V_{CC}	V	
High level output current	I_{OH}	—	−12	mA	$V_{CC} = 2.3\text{ V}$
		—	−12		$V_{CC} = 2.7\text{ V}$
		—	−24		$V_{CC} = 3.0\text{ V}$
Low level output current	I_{OL}	—	12	mA	$V_{CC} = 2.3\text{ V}$
		—	12		$V_{CC} = 2.7\text{ V}$
		—	24		$V_{CC} = 3.0\text{ V}$
Input transition rise or fall rate	$\Delta t / \Delta v$	0	10	ns / V	
Operating temperature	T_a	−40	85	$^\circ\text{C}$	

Note: Unused control inputs must be held high or low to prevent them from floating.

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Logic Diagram



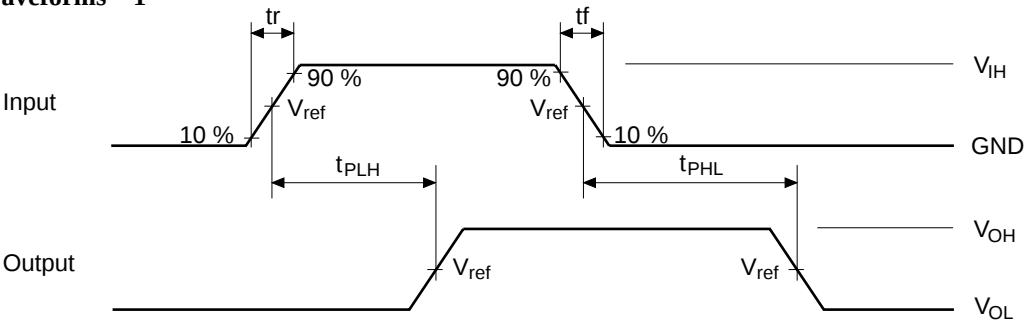
Electrical Characteristics ($T_a = -40$ to 85°C)

Item	Symbol	V_{CC} (V) ^{*1}	Min	Max	Unit	Test Conditions
Input voltage	V_{IH}	2.3 to 2.7	1.7	—	V	
		2.7 to 3.6	2.0	—		
	V_{IL}	2.3 to 2.7	—	0.7		
		2.7 to 3.6	—	0.8		
Output voltage	V_{OH}	Min to Max	$V_{CC}-0.2$	—	V	$I_{OH} = -100\ \mu\text{A}$
		2.3	2.0	—		$I_{OH} = -6\ \text{mA}$, $V_{IH} = 1.7\ \text{V}$
		2.3	1.7	—		$I_{OH} = -12\ \text{mA}$, $V_{IH} = 1.7\ \text{V}$
		2.7	2.2	—		$I_{OH} = -12\ \text{mA}$, $V_{IH} = 2.0\ \text{V}$
		3.0	2.4	—		$I_{OH} = -12\ \text{mA}$, $V_{IH} = 2.0\ \text{V}$
		3.0	2.0	—		$I_{OH} = -24\ \text{mA}$, $V_{IH} = 2.0\ \text{V}$
	V_{OL}	Min to Max	—	0.2		$I_{OL} = 100\ \mu\text{A}$
		2.3	—	0.4		$I_{OL} = 6\ \text{mA}$, $V_{IL} = 0.7\ \text{V}$
		2.3	—	0.7		$I_{OL} = 12\ \text{mA}$, $V_{IL} = 0.7\ \text{V}$
		2.7	—	0.4		$I_{OL} = 12\ \text{mA}$, $V_{IL} = 0.8\ \text{V}$
		3.0	—	0.55		$I_{OL} = 24\ \text{mA}$, $V_{IL} = 0.8\ \text{V}$
Input current	I_{IN}	3.6	—	± 5	μA	$V_{IN} = V_{CC}$ or GND
	$I_{IN(\text{hold})}$	2.3	45	—		$V_{IN} = 0.7\ \text{V}$
		2.3	-45	—		$V_{IN} = 1.7\ \text{V}$
		3.0	75	—		$V_{IN} = 0.8\ \text{V}$
		3.0	-75	—		$V_{IN} = 2.0\ \text{V}$
		3.6	—	± 500		$V_{IN} = 0$ to $3.6\ \text{V}$
Off state output current ^{*2} I_{OZ}		3.6	—	± 10	μA	$V_{OUT} = V_{CC}$ or GND
Quiescent supply current	I_{CC}	3.6	—	40	μA	$V_{IN} = V_{CC}$ or GND
	ΔI_{CC}	3.0 to 3.6	—	750	μA	$V_{IN} =$ one input at $(V_{CC}-0.6)\ \text{V}$, other inputs at V_{CC} or GND

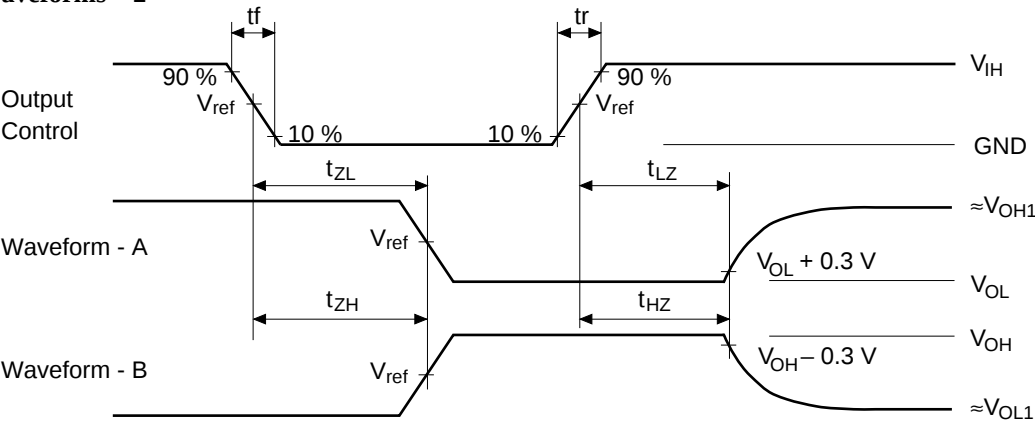
Notes: 1. For conditions shown as Min or Max, use the appropriate values under recommended operating conditions.

2. For I/O ports, the parameter I_{OZ} includes the input leakage current.

• Waveforms – 1



• Waveforms – 2



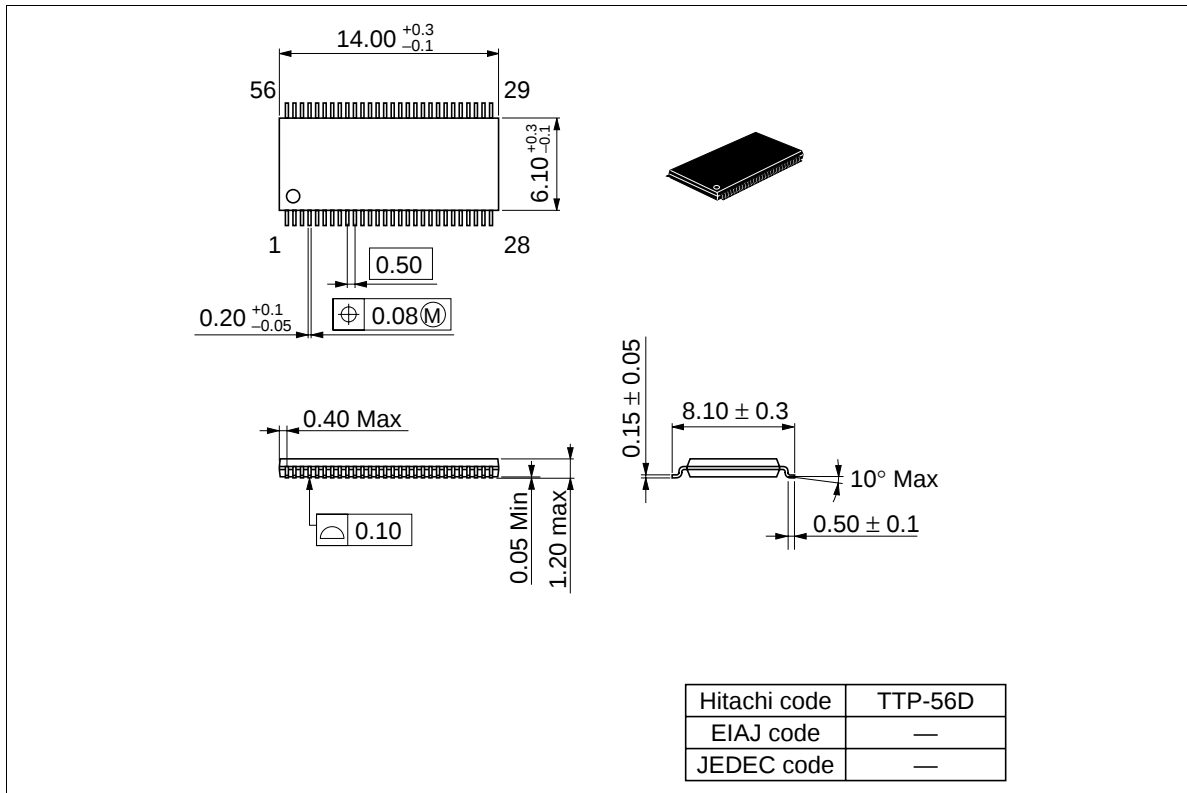
TEST	$V_{CC}=2.5\pm0.2V$	$V_{CC}=2.7V, 3.3\pm0.3V$
V_{IH}	2.3 V	2.7 V
V_{ref}	1.2 V	1.5 V
V_{OH1}	2.3 V	3.0 V
V_{OL1}	GND	GND

- Notes:
1. All input pulses are supplied by generators having the following characteristics:
 $PRR \leq 10 \text{ MHz}$, $Z_o = 50 \Omega$, $t_r \leq 2.5 \text{ ns}$, $t_f \leq 2.5 \text{ ns}$.
 2. Waveform – A is for an output with internal conditions such that the output is low except when disabled by the output control.
 3. Waveform – B is for an output with internal conditions such that the output is high except when disabled by the output control.
 4. The output are measured one at a time with one transition per measurement.

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Package Dimensions

Unit : mm



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